

## Features

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- Green Device Available

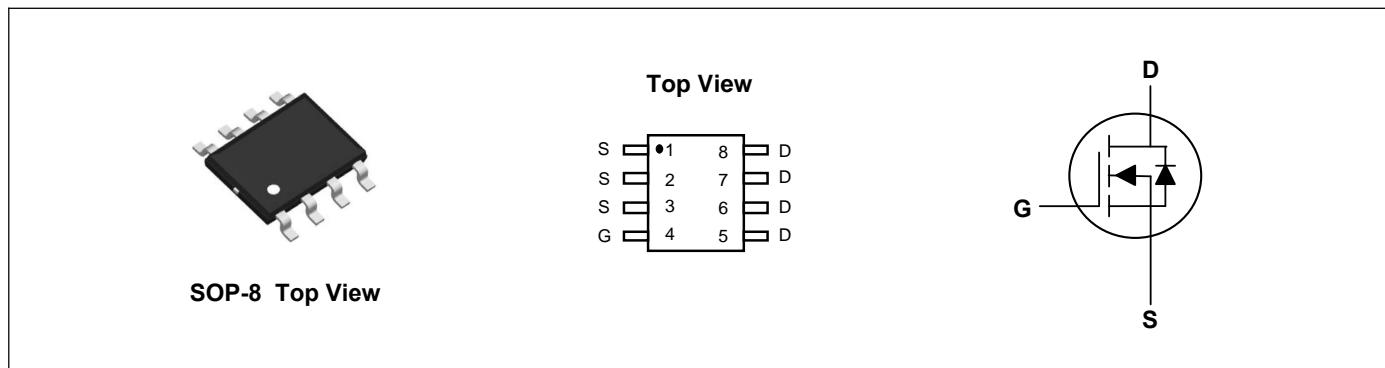
## Product Summary



$V_{DS}$	30	V
$I_D$	10	A
$R_{DS(ON)}$ (at $V_{GS}=10V$ )	12	mΩ
$R_{DS(ON)}$ (at $V_{GS}=4.5V$ )	16	mΩ

## Applications

- High Frequency Point-of-Load,Synchronous Buck Converter
- Networking DC-DC Power System
- Load Switch



## Absolute Maximum Ratings( $T_A=25^\circ C$ , unless otherwise noted)

Parameter	Symbol	Rating	Units
Drain-Source Voltage	$V_{DS}$	30	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current <sup>1</sup>	$I_D$	10	A
Continuous Drain Current <sup>1</sup>	$I_D @ T_C = 100^\circ C$	6	A
Pulsed Drain Current <sup>2</sup>	$I_{DM}$	50	A
Total Power Dissipation <sup>3</sup>	$P_D$	2.5	W
Storage Temperature Range	$T_{STG}$	-55 to 150	°C
Operating Junction Temperature Range	$T_J$	-55 to 150	°C

## Thermal Characteristics

Parameter	Symbol	Typ	Max	Unit
Thermal Resistance Junction-Case <sup>1</sup>	$R_{\theta JC}$	---	50	°C/W

**Electrical Characteristics ( $T_J=25^\circ\text{C}$ , unless otherwise noted)**

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	$\text{BV}_{\text{DSS}}$	$V_{\text{GS}}=0\text{V}$ , $I_D=250\mu\text{A}$	30	---	---	V
Static Drain-Source On-Resistance	$R_{\text{DS}(\text{ON})}$	$V_{\text{GS}}=10\text{V}$ , $I_D=10\text{A}$	---	8	12	$\text{m}\Omega$
		$V_{\text{GS}}=4.5\text{V}$ , $I_D=5\text{A}$	---	11	16	$\text{m}\Omega$
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{GS}}=V_{\text{DS}}$ , $I_D=250\mu\text{A}$	1	1.6	3	V
Drain-Source Leakage Current	$I_{\text{DSS}}$	$V_{\text{DS}}=30\text{V}$ , $V_{\text{GS}}=0\text{V}$ , $T_J=25^\circ\text{C}$	---	---	1	$\mu\text{A}$
Gate-Source Leakage Current	$I_{\text{GSS}}$	$V_{\text{GS}}=\pm 20\text{V}$ , $V_{\text{DS}}=0\text{V}$	---	---	$\pm 100$	nA
Forward Transconductance	$g_{\text{fs}}$	$V_{\text{DS}}=5\text{V}$ , $I_D=10\text{A}$	15	---	---	S
Total Gate Charge	$Q_g$	$V_{\text{DS}}=15\text{V}$ , $V_{\text{GS}}=10\text{V}$ , $I_D=5\text{A}$	---	13	---	nC
Gate-Source Charge	$Q_{\text{gs}}$		---	5.5	---	
Gate-Drain Charge	$Q_{\text{gd}}$		---	3.5	---	
Turn-On Delay Time	$T_{\text{d(on)}}$	$V_{\text{DD}}=25\text{V}$ , $R_G=6\Omega$ , $V_{\text{GS}}=10\text{V}$ , $I_D=5\text{A}$	---	30	---	ns
Rise Time	$T_r$		---	20	---	
Turn-Off Delay Time	$T_{\text{d(off)}}$		---	100	---	
Fall Time	$T_f$		---	80	---	
Input Capacitance	$C_{\text{iss}}$	$V_{\text{DS}}=15\text{V}$ , $V_{\text{GS}}=0\text{V}$ , $f=1\text{MHz}$	---	1550	---	pF
Output Capacitance	$C_{\text{oss}}$		---	300	---	
Reverse Transfer Capacitance	$C_{\text{rss}}$		---	180	---	

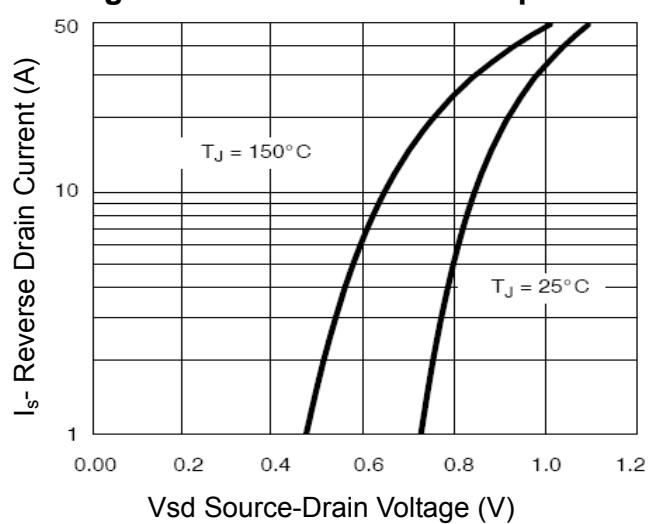
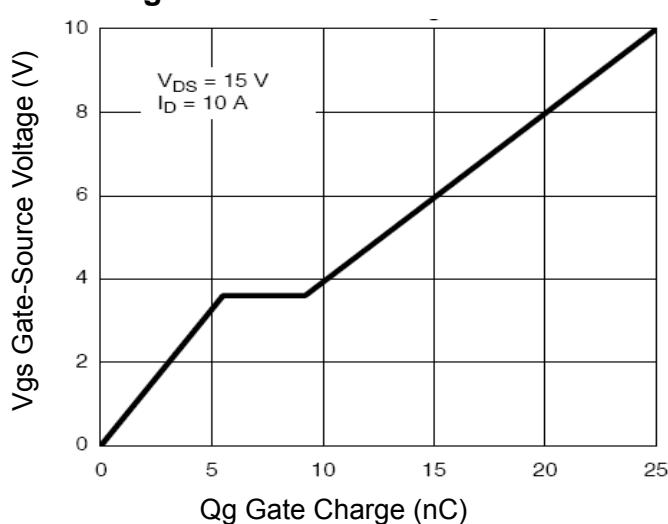
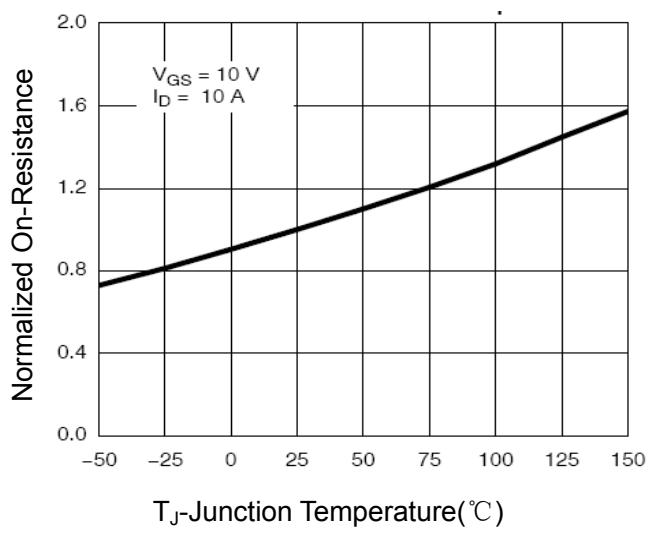
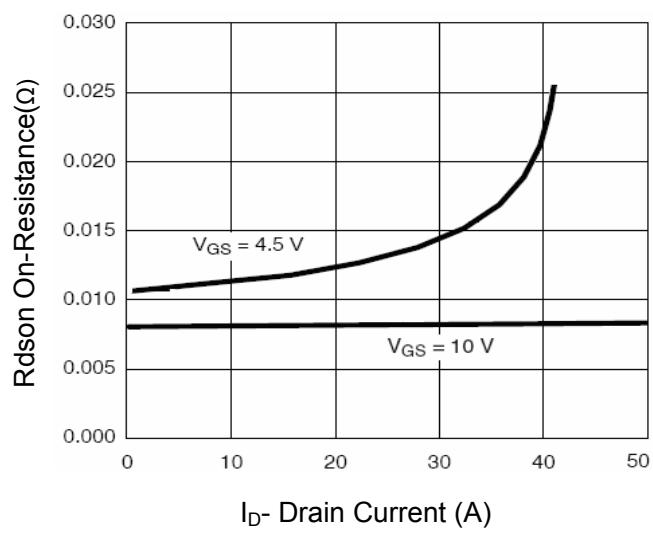
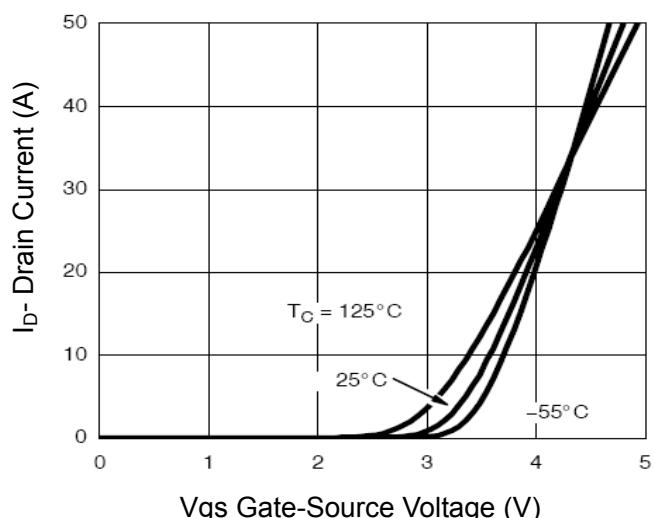
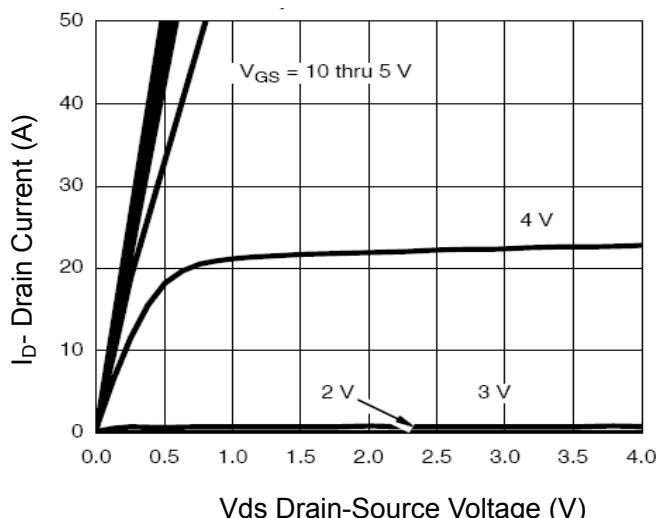
**Drain-Source Diode Characteristics**

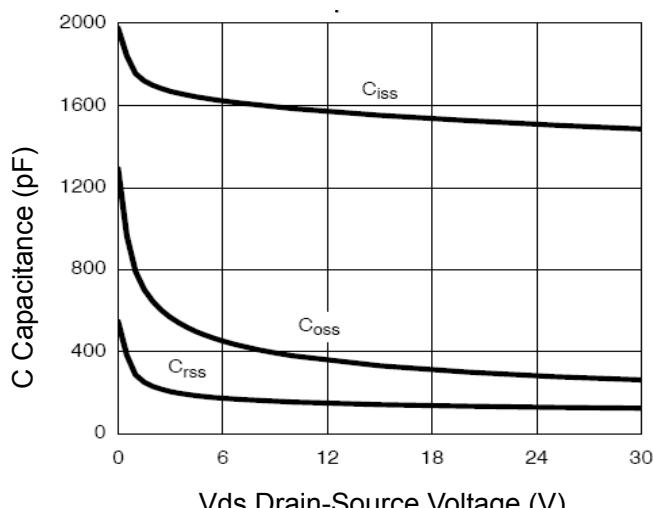
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Continuous Source Current <sup>2</sup>	$I_s$		---	---	10	A
Diode Forward Voltage <sup>1</sup>	$V_{\text{SD}}$	$V_{\text{GS}}=0\text{V}$ , $I_s=10\text{A}$ , $T_J=25^\circ\text{C}$	---	---	1.2	V

**Note:**

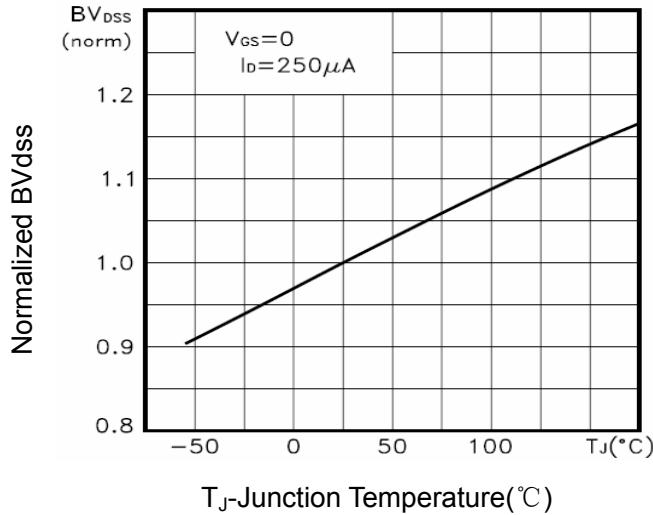
- 1.The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper.
- 2.The data tested by pulsed , pulse width  $\leq 300\mu\text{s}$  , duty cycle  $\leq 2\%$
- 3.The power dissipation is limited by  $150^\circ\text{C}$  junction temperature

## Typical Characteristics

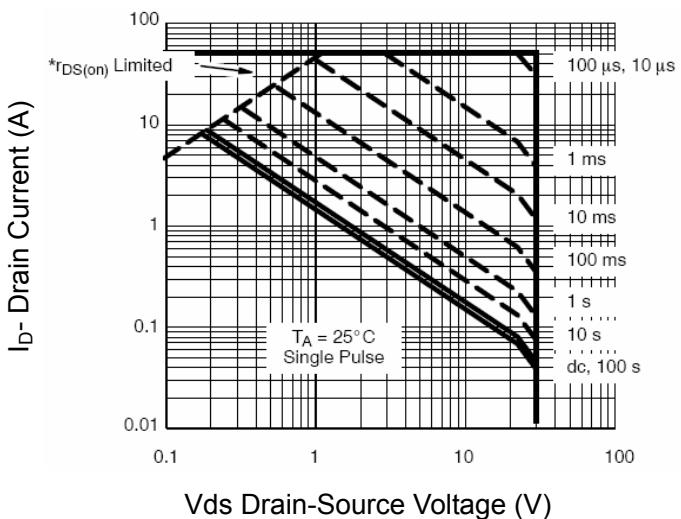




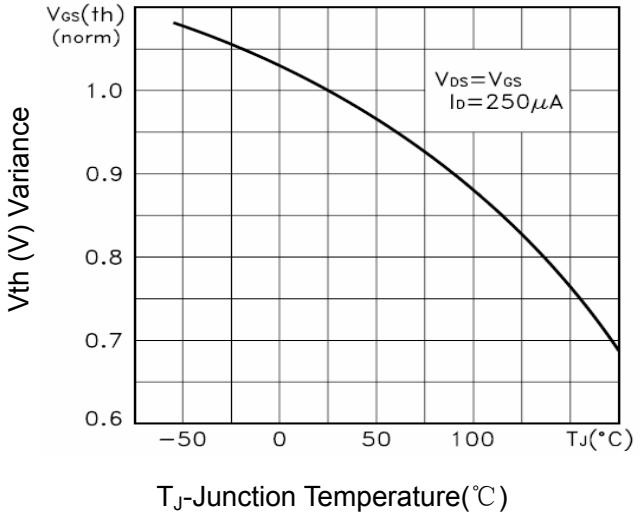
**Figure 7 Capacitance vs Vds**



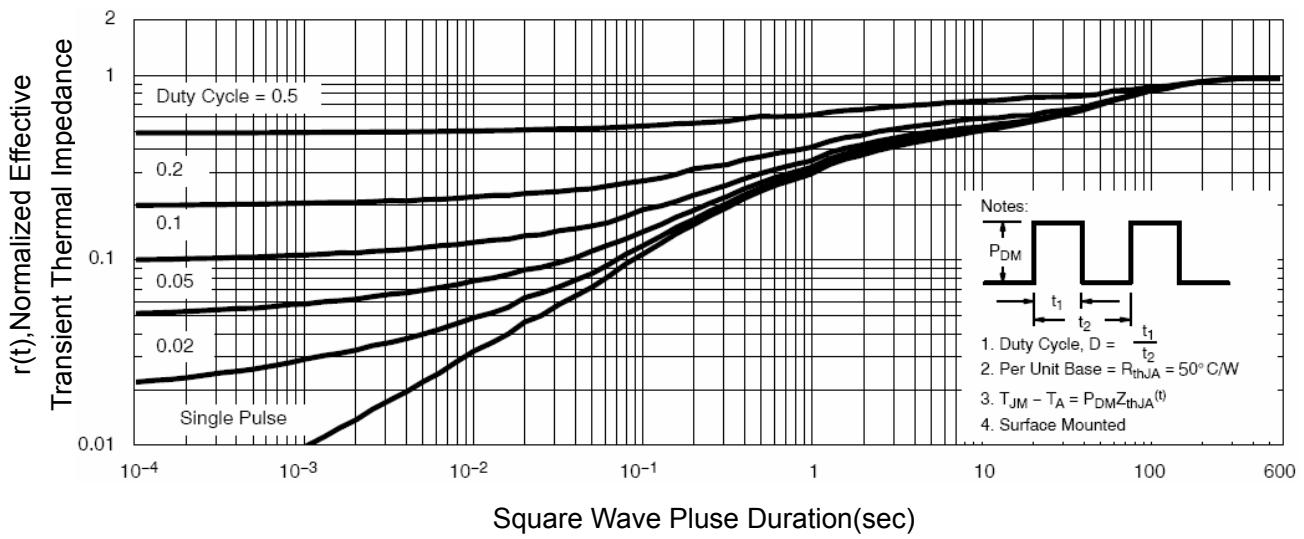
**Figure 9  $BV_{DSS}$  vs Junction Temperature**



**Figure 8 Safe Operation Area**

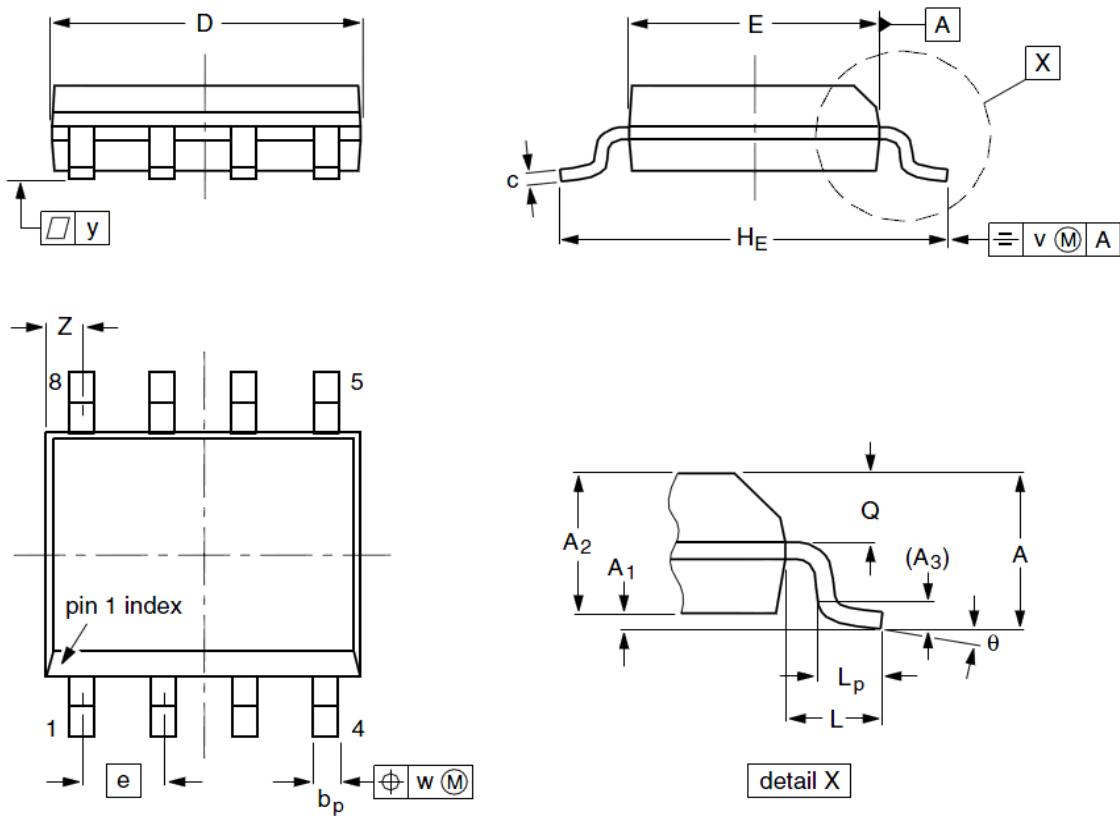


**Figure 10  $V_{GS(th)}$  vs Junction Temperature**



**Figure 11 Normalized Maximum Transient Thermal Impedance**

### SOP-8 Package Outline Dimensions



<b>Symbol</b>	<b>Dimensions (unit:mm)</b>			<b>Symbol</b>	<b>Dimensions (unit:mm)</b>		
	<b>Min</b>	<b>Typ</b>	<b>Max</b>		<b>Min</b>	<b>Typ</b>	<b>Max</b>
<b>A</b>	1.35	1.55	1.75	<b>A<sub>1</sub></b>	0.10	0.18	0.25
<b>A<sub>2</sub></b>	1.25	1.45	1.65	<b>A<sub>3</sub></b>	--	0.25	--
<b>b<sub>p</sub></b>	0.36	0.42	0.51	<b>c</b>	0.19	0.22	0.25
<b>D</b>	4.70	4.92	5.10	<b>E</b>	3.80	3.90	4.00
<b>e</b>	--	1.27	--	<b>H<sub>E</sub></b>	5.80	6.00	6.20
<b>L</b>	--	1.05	--	<b>L<sub>P</sub></b>	0.40	0.68	1.00
<b>Q</b>	0.60	0.65	0.73	<b>v</b>	--	0.25	--
<b>w</b>	--	0.25	--	<b>y</b>	--	0.10	--
<b>Z</b>	0.30	0.50	0.70	<b>θ</b>	0°		8°